## NSN 5961-01-147-2386

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#### **Inclosure Material:**

Metal

#### Overall Length:

Between 0.790 inches and 0.810 inches

#### **Overall Height:**

Between 0.085 inches and 0.105 inches

#### **Overall Width:**

Between 0.252 inches and 0.268 inches

#### **End Application:**

5820-01-048-9110

#### Mounting Facility Quantity:

2

Internal Configuration:

#### Junction contact

**Mounting Method:** 

#### Unthreaded hole

### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.5 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

44.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Precious Material And Location:**

Terminals and base surface gold

#### **Precious Material:**

Gold

#### **Terminal Type And Quantity:**

1 flange and 2 ribbon

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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